TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC74F,TC74VHC74FN,TC74VHC74FT,TC74VHC74FK

#### Dual D-Type Flip-Flop with Preset and Clear

The TC74VHC74 is an advanced high speed CMOS D-FLIP FLOP fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.

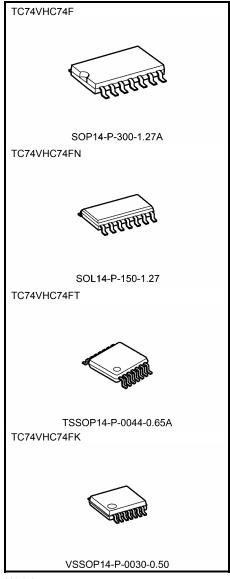
 $\overline{\text{CLR}}$  and  $\overline{\text{PR}}$  are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

- High speed:  $f_{max} = 170 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $ICC = 2 \mu A \text{ (max)}$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: t<sub>p</sub>LH ≃ t<sub>p</sub>HL
- Wide operating voltage range: VCC (opr) = 2 V to 5.5 V
- Pin and function compatible with 74ALS74

Note: The JEDEC SOP (FN) is not available in Japan.



Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

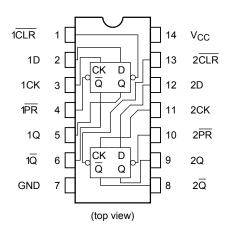
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

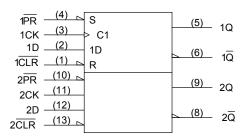
 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

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#### **Pin Assignment**



#### **IEC Logic Symbol**



#### **Truth Table**

	Inp	uts		Out	puts	Function		
CLR	PR	D	CK	Q	Q	Function		
L	Н	Х	Х	L	Н	Clear		
Н	L	Х	Х	Η	Ь	Preset		
L	L	Χ	Х	Н	Н			
Н	Н	L		L	Н	_		
Н	Н	Н		Н	L	_		
Н	Н	Х	$\Box$	Q <sub>n</sub>	$\overline{\overline{Q}}_n$	No Change		

X: Don't care

### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	VIN	−0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	lıK	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	٧	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V	
input noe and ian unie	uuuv	0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V)		

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
, , , ,					Min	Тур.	Max	Min	Max	
High-level input		-		2.0	1.50	_	_	1.50	_	V
voltage	V <sub>IH</sub>			3.0 to 5.5	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	
Low-level input		_		2.0	_	_	0.50	_	0.50	٧
voltage	V <sub>IL</sub>			3.0 to 5.5	_	_	V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	
	Voн			2.0	1.9	2.0	_	1.9	_	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5	_	4.4	_	V
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	2.48	_	
			I <sub>OH</sub> = -8 mA	4.5	3.94	_	_	3.80	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	_	0.0	0.1	_	0.1	
			I <sub>OL</sub> = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage				4.5	_	0.0	0.1	_	0.1	V
			I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	ı	±1.0	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2.0	_	20.0	μΑ



### Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C	Ta = -40 to 85°C	Unit	
			V <sub>CC</sub> (V)	Limit	Limit	
Minimum pulse width	t <sub>w (L)</sub>		$3.3 \pm 0.3$	6.0	7.0	ne
(CK)	t <sub>w (H)</sub>	_	$5.0 \pm 0.5$	5.0	5.0	ns
Minimum pulse width	<b>4</b>		$3.3 \pm 0.3$	6.0	7.0	20
$(\overline{CLR},\overline{PR})$	t <sub>w (L)</sub>	_	$5.0 \pm 0.5$	5.0	5.0	ns
Minimum act un time	4		$3.3 \pm 0.3$	6.0	7.0	20
Minimum set-up time	t <sub>s</sub>	_	5.0 ± 0.5	5.0	5.0	ns
Minimum hald time			$3.3 \pm 0.3$	0.5	0.5	
Minimum hold time	t <sub>h</sub>	_	$5.0 \pm 0.5$	0.5	0.5	ns
Minimum removal time	4		$3.3 \pm 0.3$	5.0	5.0	20
(CLR, PR)	t <sub>rem</sub>	_	$5.0 \pm 0.5$	3.0	3.0	ns

### AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			-	Га = 25°(	)	Ta = -40 to 85°C		Unit
	.,		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	6.7	11.9	1.0	14.0	- ns
Propagation delay time	t <sub>pLH</sub>			50	_	9.2	15.4	1.0	17.5	
(CK-Q, $\overline{Q}$ )	t <sub>pHL</sub>	_	5.0 ± 0.5	15	_	4.6	7.3	1.0	8.5	
			5.0 ± 0.5	50	_	6.1	9.3	1.0	10.5	
	t <sub>PLH</sub>	_	3.3 ± 0.3	15	_	7.6	12.3	1.0	14.5	- ns
Propagation delay time				50	_	10.1	15.8	1.0	18.0	
(CLR, PR-Q, Q)			5.0 ± 0.5	15	_	4.8	7.7	1.0	9.0	
				50	_	6.3	9.7	1.0	11.0	
	f <sub>max</sub>	_	3.3 ± 0.3	15	80	125	_	70	_	
Maximum clock				50	50	75	_	45	_	MHz
frequency			5.0 ± 0.5	15	130	170	_	110	_	IVIITZ
				50	90	115	_	75	_	
Input capacitance	C <sub>IN</sub>		_		_	4	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>			(Note)	_	25	_	_	_	pF

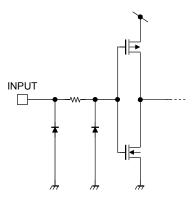
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 (per F/F)$$



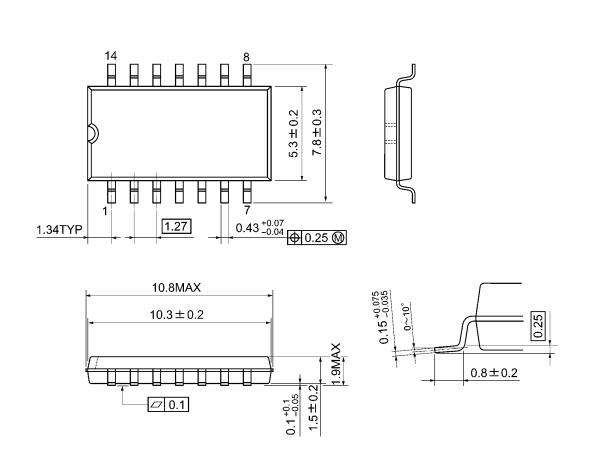
# **Input Equivalent Circuit**



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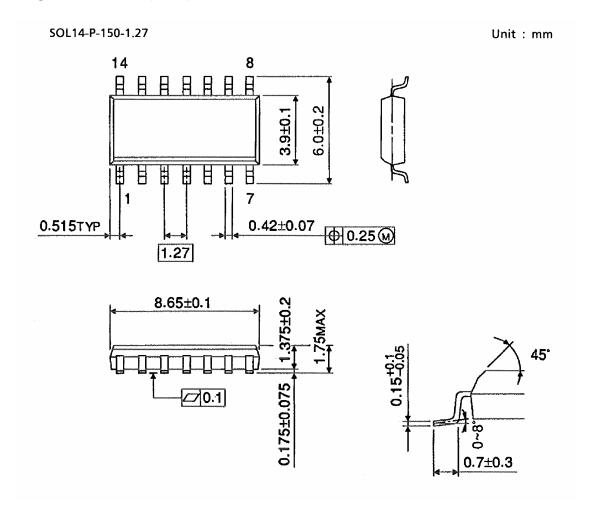
# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

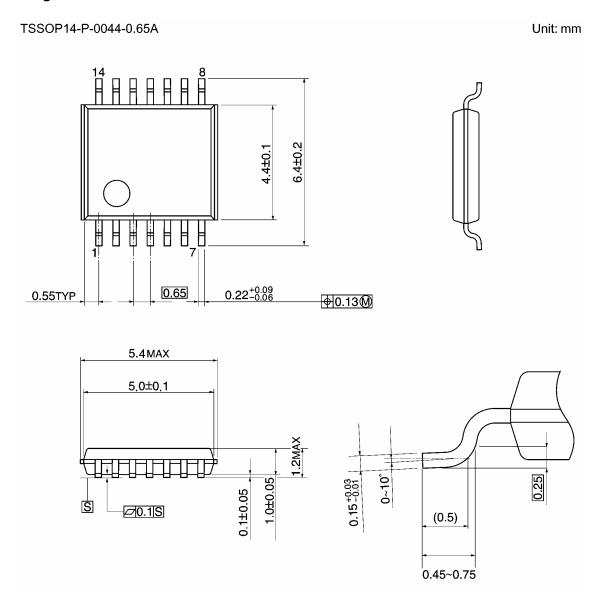
### **Package Dimensions (Note)**



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

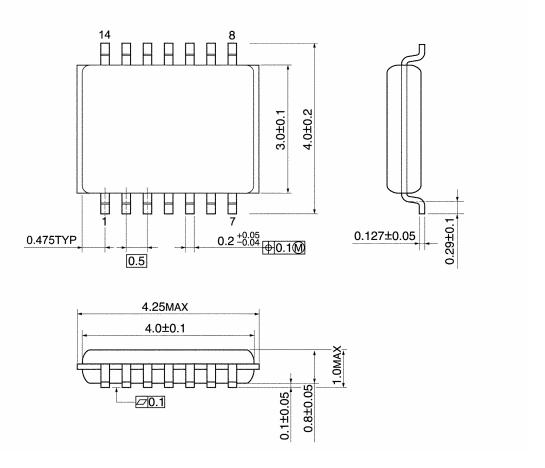
# **Package Dimensions**



Weight: 0.06 g (typ.)

# **Package Dimensions**

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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